

CLC109

Low-Power, Wideband, Closed-Loop Buffer

General Description

The CLC109 is a high-performance, closed-loop monolithic buffer intended for power sensitive applications. Requiring only 35mW of quiescent power ($\pm 5V$ supplies), the CLC109 offers a high bandwidth of 270MHz (0.5V_{pp}) and a slew rate of 350V/ μ s. Even with this minimal dissipation, the CLC109 can easily drive a demanding 100 Ω load. The buffer specifications are for a 100 Ω load.

With its patented closed-loop topology, the CLC109 has significant performance advantages over conventional open-loop designs. Applications requiring low (2.8 Ω) output impedance and nearly ideal unity gain (0.997) through very high frequencies will benefit from the CLC109's superior performance. Power sensitive applications will benefit from the CLC109's excellent performance on reduced or single supply voltages.

Constructed using an advanced, complementary bipolar process and Comlinear's proven high-performance architectures, the CLC109 is available in several versions to meet a variety of requirements.

CLC109AJP	-40°C to +85°C	8-pin Plastic DIP
CLC109AJE	-40°C to +85°C	8-pin Plastic SOIC
CLC109ALC	-40°C to +85°C	dice
CLC109AMC	-55°C to +125°C	dice qualified to Method 5008, MIL-STD-883, Level B
CLC109AJM5	-40°C to +85°C	5-pin SOT

Contact factory for other packages and DESC SMD number.

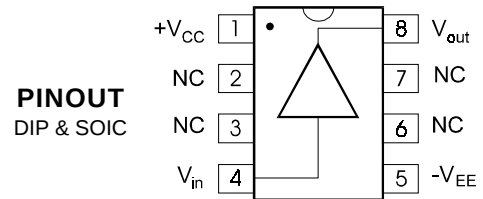
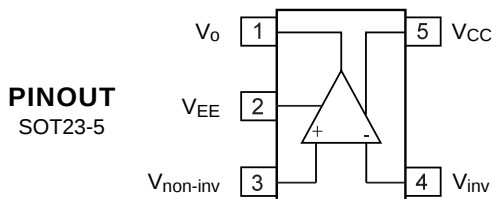
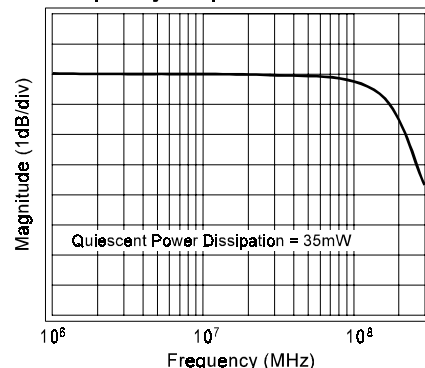
Features

- High small-signal bandwidth (270MHz)
- Low supply current (3.5mA @ $\pm 5V$)
- Low output impedance (2.8 Ω)
- 350V/ μ s slew rate
- Single supply operation (0 to 3V supply min.)
- Evaluation boards and Spice models

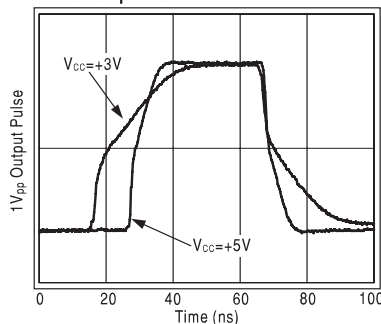
Applications

- Video switch buffers
- Test point drivers
- Low power active filters
- DC clamping buffer
- High-speed S & H circuits
- Inverting op amp input buffer

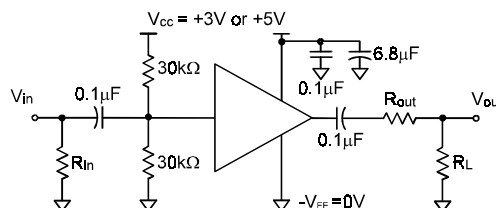
Frequency Response for $\pm 5V$



Pulse Response

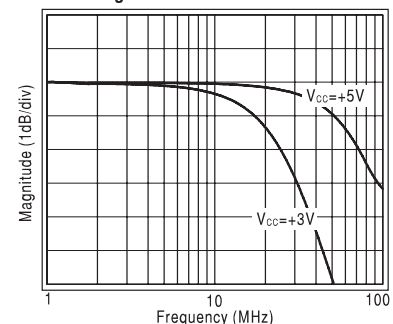


Typical Application



Single-Supply Circuit

Small-Signal Bandwidth



CLC109 Electrical Characteristics ($\pm V_{CC} = \pm 5V$, $R_L = 100\Omega$ unless specified)

PARAMETER	CONDITIONS	TYP	MIN/MAX RATINGS			UNITS	SYMBOL
Ambient Temperature	CLC109AJ	+25°C	-40°C	+25°C	+85°C		
FREQUENCY RESPONSE							
small signal bandwidth	$V_{out} < 0.5V_{pp}$	270	200	200	150	MHz	SSBW
	$V_{out} < 2.0V_{pp}$	120	90	90	70	MHz	LSBW
gain flatness	$V_{out} < 0.5V_{pp}$	0	± 0.1	± 0.1	± 0.1	dB	GFL
flatness	DC-30MHz	0	1.0	0.3	0.3	dB	GFPH
peaking	DC-200MHz	0.1	0.4	0.4	0.6	dB	GFRH
rolloff	DC-60MHz	0.7	1.5	1.0	1.0	%	DG
differential gain	4.43MHz, 150 Ω load	0.03	0.05	0.05	0.1	°	DP
differential phase	4.43MHz, 150 Ω load						
TIME DOMAIN RESPONSE							
rise and fall time	0.5V step	1.3	1.7	1.7	2.3	ns	TRS
	2.0V step	4.4	6	6	7	ns	TRL
settling time to $\pm 0.05\%$	2.0V step	12	25	18	25	ns	TS
overshoot	0.5V step	3	15	10	10	%	OS1
slew rate	4V step	350	220	250	220	V/ μ sec	SR
DISTORTION AND NOISE PERFORMANCE							
2nd harmonic distortion	2V _{pp} , 20MHz	-46	-36	-38	-38	dBc	HD2
3rd harmonic distortion	2V _{pp} , 20MHz	-55	-50	-50	-45	dBc	HD3
equivalent output noise							
voltage		3.3	4.1	4.1	4.5	nV/ $\sqrt{Hz}$	VN
current		1.3	3	2	2	pA/ $\sqrt{Hz}$	ICN
STATIC DC PERFORMANCE							
small signal gain	no load	0.997	0.995	0.995	0.994	V/V	GA1
	100 Ω load	0.96	0.94	0.95	0.95	V/V	GA2
output resistance	DC	2.8	5.0	4.0	4.0	Ω	RO
*output offset voltage		1	± 8.2	± 5	± 6	mV	VIO
average temperature coefficient		± 10	± 40		± 30	$\mu V/^\circ C$	DVIO
*input bias current		± 2	± 8	± 4	± 4	μA	IBN
average temperature coefficient		± 30	± 50		± 25	nA/ $^\circ C$	DIBN
power supply rejection ratio		-56	-48	-48	-46	dB	PSRR
*supply current	no load	3.5	4	4	4	mA	ICC
MISCELLANEOUS PERFORMANCE							
integral endpoint linearity	$\pm 1V$, full scale	0.5	1.0	0.7	0.6	%	ILIN
input resistance		1.5	0.3	1.0	2.0	M Ω	RIN
input capacitance	CERDIP	2.5	3.5	3.5	3.5	pF	CIN
	Plastic DIP	1.25	2.0	2.0	2.0	pF	CIN
output voltage range	no load	4.0	3.6	3.8	3.8	V	VO
	$R_L = 100\Omega$	+3.8,-2.5	+3.0,-1.2	+3.6,-2.0	+3.6,-2.5	V	VOL
	$R_L = 100\Omega$, 0°C		+3.0,-1.6			V	VOL
output current		+60,-30	+40,-12	+40,-20	+40,-30	mA	IO
	0°C		+40,-16			mA	IO

Min/max ratings are based on product characterization and simulation. Individual parameters are tested as noted. Outgoing quality levels are determined from tested parameters.

Absolute Maximum Ratings

V_{CC}	$\pm 7.0V$
I_{out}	30mA
output is short circuit protected to ground, but maximum reliability will be maintained if I_{out} does not exceed...	$\pm V_{CC}$
input voltage	+150°C
maximum junction temperature	
operating temperature range	
AJ	-40°C to +85°C
A8/AM/AL	-55°C to +125°C
storage temperature range	-65°C to +150°C
lead temperature (soldering 10 sec)	+300°C
ESD rating	1000V

Miscellaneous Ratings

Notes:
* AJ : 100% tested at +25°C.

Package Thermal Resistance

Package	θ_{JC}	θ_{JA}
Plastic (AJP)	70°C/W	125°C/W
Surface Mount (AJE)	65°C/W	145°C/W
SOT	130°C/W	200°C/W

Reliability Information

Transistor count

17

Electrical Characteristics ($V_{CC}=+3V$ or $V_{CC}=+5V$, $-V_{EE}=0V$, $T_A=+25^{\circ}C$, $R_L=100\Omega$, unless noted)

PARAMETERS	CONDITIONS	$V_{CC}=3V$	$V_{CC}=5V$	UNITS
FREQUENCY DOMAIN RESPONSE				
-3dB bandwidth	$V_{out} < 0.5V_{pp}$	30	90	MHz
	$V_{out} < 2.0V_{pp}$		35	MHz
gain flatness	$V_{out} < 0.5V_{pp}$			
flatness	DC to 30MHz	3	0.3	dB
peaking	DC to 200MHz	0	0	dB
rolloff	DC to 60MHz		1.5	dB
TIME DOMAIN RESPONSE				
rise and fall time	0.5V step	13.9	4.7	ns
	2.0V step		13.5	ns
overshoot	0.5V step	0	0	%
slew rate	0.5V step	35	200	V/ μ s
DISTORTION AND NOISE RESPONSE				
2 nd harmonic distortion	0.5V _{pp} , 20MHz	-32		dBc
	1.0V _{pp} , 20MHz		-37	dBc
3 rd harmonic distortion	0.5V _{pp} , 20MHz	-29		dBc
	1.0V _{pp} , 20MHz		-43	dBc
STATIC DC PERFORMANCE				
small-signal gain	AC-coupled	0.89	0.94	V/V
supply current	$R_L = \infty$	0.75	1.6	mA
MISCELLANEOUS PERFORMANCE				
output voltage range	$R_L = \infty$	1.5	2.8	V_{pp}
	$R_L=100\Omega$	1.1	2.6	V_{pp}

Operation

The CLC109 is a low-power, high-speed unity-gain buffer. It uses a closed-loop topology which allows for accuracy not usually found in high-speed buffers. A closed-loop design provides high accuracy and low output impedance through a wide bandwidth.

Single Supply Operation

Although the CLC109 is specified to operate from split $\pm 5V$ power supplies, there is no internal ground reference that prevents operation from a single voltage power supply. For single supply operation the input signal should be biased at a DC value of $\frac{1}{2}V_{CC}$. This can be accomplished by AC coupling and rebiasing as shown in the "Typical Application" illustrations on the front page.

The above electrical specifications provide typical performance specifications for the CLC109 at $25^{\circ}C$ while operating from a single +3V or a single +5V power supply.

Printed Circuit Layout and Supply Bypassing

As with any high-frequency device, a good PCB layout is required for optimum performance. This is especially important for a device as fast as the CLC109.

To minimize capacitive feedthrough, pins 2, 3, 6, and 7 should be connected to the ground plane, as shown in Figure 1. Input and output traces should be laid out as transmission lines with the appropriate termination resistors very near the CLC109. On a 0.065 inch epoxy PCB material, a 50 Ω transmission line (commonly called stripline) can be constructed by using a trace width of 0.1" over a complete ground plane.

Figure 1 shows recommended power supply bypassing.

Parasitic or load capacitance directly on the output of the CLC109 will introduce additional phase shift in the device.

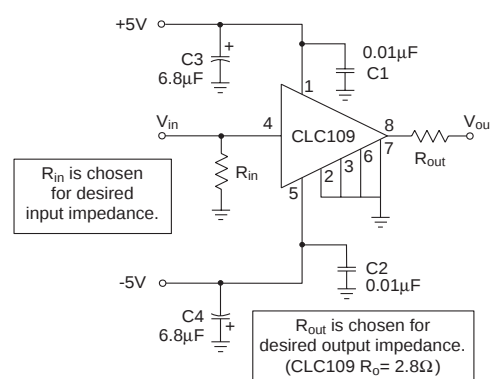


Figure 1: Recommended circuit & evaluation board schematic

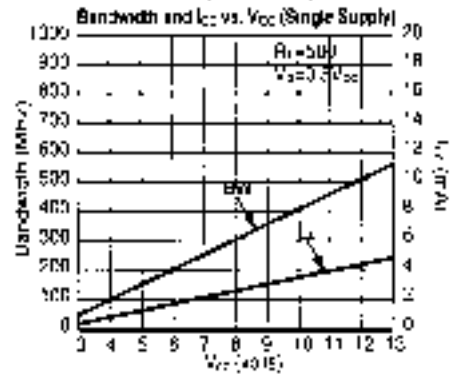
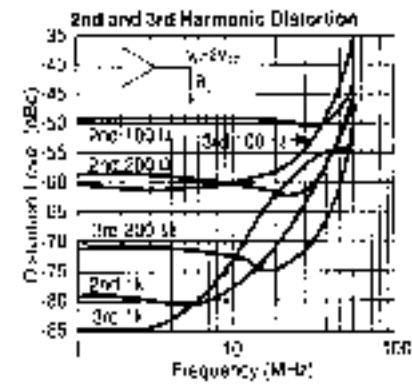
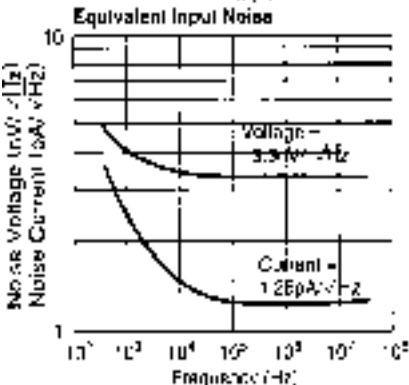
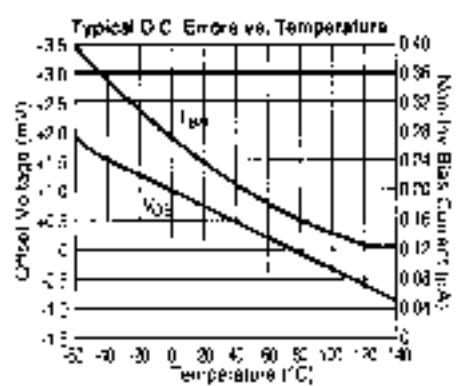
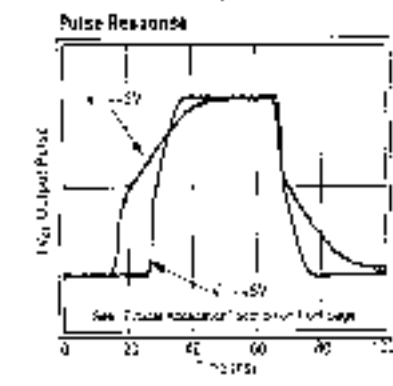
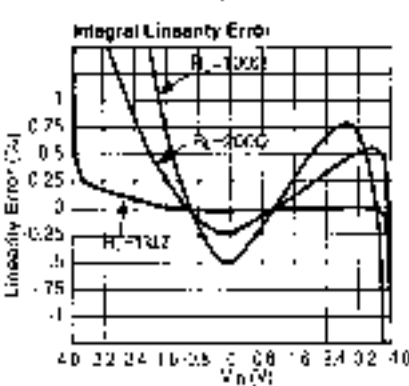
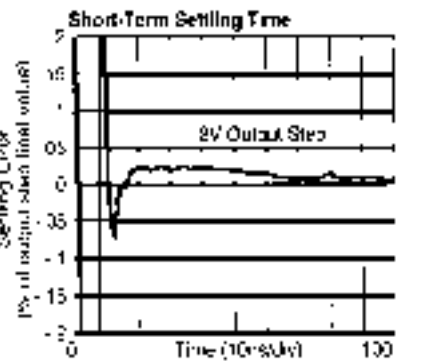
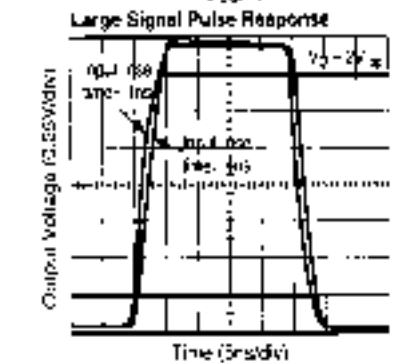
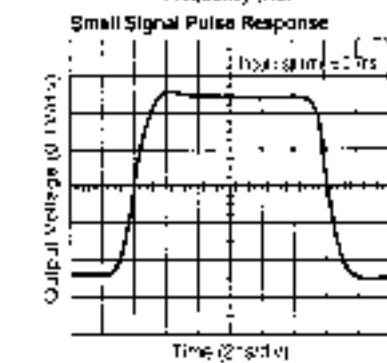
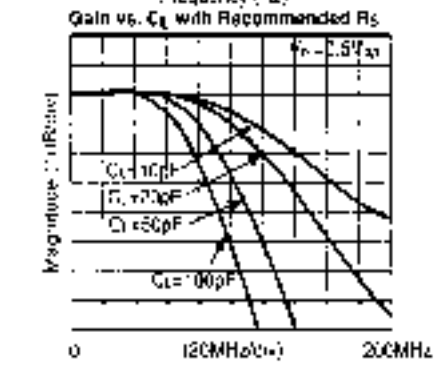
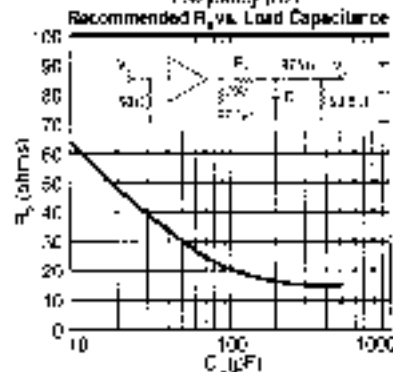
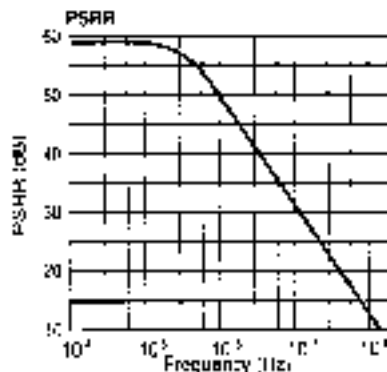
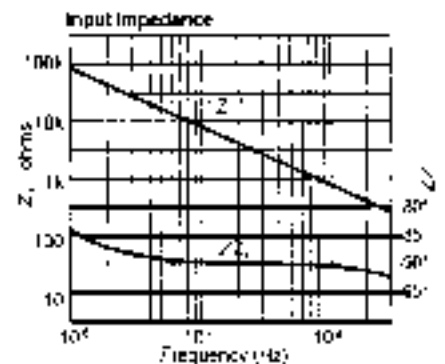
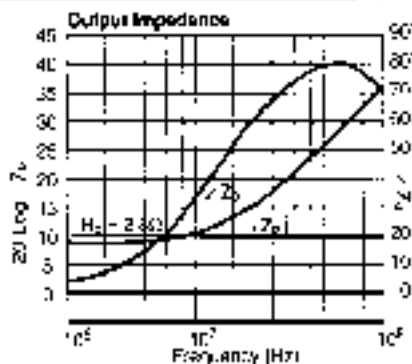
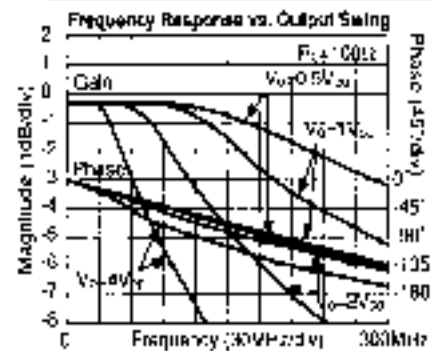
This phase shift can decrease phase margin and increase frequency response peaking. A small series resistor inserted between pin 6 and the capacitance effectively decouples this effect. The graphs on the following page illustrate the required resistor value and the resulting performance vs. capacitance.

Precision buffered resistors (PRP8351 series from Precision Resistive Products), which have low parasitic reactances, were used to develop the data sheet specifications. Precision carbon composition resistors or standard spirally-trimmed RN55D metal film resistors will work, though they may cause a slight degradation of ac performance due to their reactive nature at high frequencies.

Evaluation Boards

Evaluation boards are available from National as part CLC730012 (DIP) and CLC730045 (SOIC). This board was used in the characterization of the device and provides optimal performance. Designers are encouraged to copy these printed circuit board layouts for their applications.

Typical Performance Characteristics ($T_A = +25^\circ\text{C}$, $V_{CC} = +5\text{V}$, $R_L = 100\Omega$ unless specified)



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